

NCE P-Channel Enhancement Mode Power MOSFET

Description

The NCE3007S uses advanced trench technology and design to provide excellent $R_{DS(ON)}$ with low gate charge. It can be used in load switch and battery protection applications.

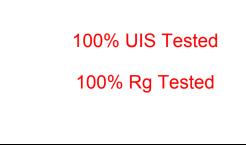
General Features

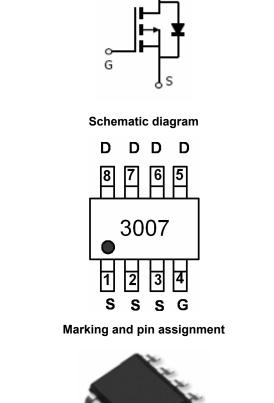
• $V_{DS} = -30V, I_D = -6.5A$ $R_{DS(ON)} < 46m\Omega @ V_{GS} = -10V$ $R_{DS(ON)} < 72m\Omega @ V_{GS} = -4.5V$

- High density cell design for ultra low Rdson
- Fully characterized avalanche voltage and current

Application

- Load switch
- battery protection





SOP-8 top view

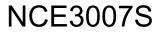
Package Marking and Ordering Information

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Device Marking	Device	Device Package Reel Size Tape width		vice Package Reel Size Tape width		
3007	NCE3007S	SOP-8	Ø330mm	12mm	2500 units	

Absolute Maximum Ratings (T_A=25℃unless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	VDS	-30	V
Gate-Source Voltage	Vgs	±20	V
Drain Current-Continuous	I _D	-6.5	А
Drain Current-Continuous(T _C =100°C)	I _D (100℃)	-4.5	А
Pulsed Drain Current	I _{DM}	-30	А
Maximum Power Dissipation	PD	3.1	W
Operating Junction and Storage Temperature Range	T _J ,T _{STG}	-55 To 150	°C





Thermal Characteristic

Thermal Resistance, Junction-to-Ambient(Note 2)	R _{θJA}	40	°C/W	
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Electrical Characteristics (T_A=25[°]C unless otherwise noted)

Parameter	Symbol	Condition	Min	Тур	Max	Unit	
Off Characteristics	····						
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V I _D =-250µA	-30	-33	-	V	
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =-30V,V _{GS} =0V	-	-	1	μA	
Gate-Body Leakage Current	I _{GSS}	$V_{GS}=\pm 20V, V_{DS}=0V$	-	-	±100	nA	
On Characteristics (Note 3)	····						
Gate Threshold Voltage	V _{GS(th)}	$V_{DS}=V_{GS}$, $I_{D}=-250\mu A$	-1.5	-1.9	-2.5	V	
Drain Course On Chate Desistence	D.	V _{GS} =-10V, I _D =-6.5A	-	30	46	mΩ	
Drain-Source On-State Resistance	R _{DS(ON)}	V _{GS} =-4.5V, I _D =-5A	-	53	72		
Forward Transconductance	g FS	V _{DS} =-5V,I _D =-6.5A	14	-	-	S	
Dynamic Characteristics (Note4)			ł			•	
Input Capacitance	C _{lss}		-	520	-	PF	
Output Capacitance	C _{oss}	V _{DS} =-15V,V _{GS} =0V,	-	100	-	PF	
Reverse Transfer Capacitance	C _{rss}	F=1.0MHz	-	65	-	PF	
Switching Characteristics (Note 4)	····						
Turn-on Delay Time	t _{d(on)}		-	7.5	-	nS	
Turn-on Rise Time	tr	V_{DD} =-15V,I _D =-4A	-	5.5	-	nS	
Turn-Off Delay Time	t _{d(off)}	V_{GS} =-10V,R _{GEN} =3 Ω	-	19	-	nS	
Turn-Off Fall Time	t _f		-	7	-	nS	
Total Gate Charge	Qg	V _{DS} =-15V,I _D =-6.5A,	-	9.2	-	nC	
Gate-Source Charge	Q _{gs}	v _{DS} =-13v,1 _D =-0.5A, V _{GS} =-10V	-	1.6	-	nC	
Gate-Drain Charge	Q _{gd}	VGS=-IUV	-	2.2	-	nC	
Drain-Source Diode Characteristics	·						
Diode Forward Voltage (Note 3)	V _{SD}	V _{GS} =0V,I _S =-6.5A	-	-	-1.2	V	
Diode Forward Current (Note 2)	ls		-	-	-6.5	А	

Notes:

1. Repetitive Rating: Pulse width limited by maximum junction temperature.

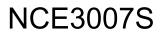
2. Surface Mounted on FR4 Board, t \leq 10 sec.

- **3.** Pulse Test: Pulse Width \leq 300µs, Duty Cycle \leq 2%.
- 4. Guaranteed by design, not subject to production

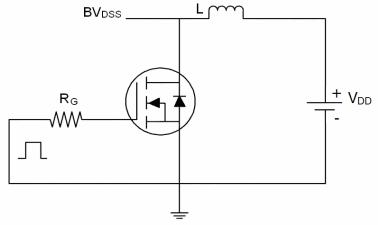


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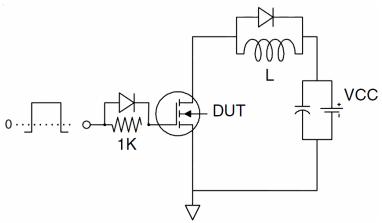
Pb Free Product



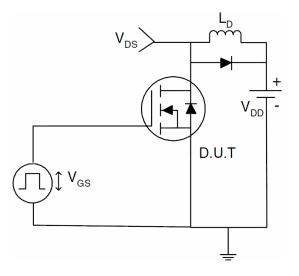
Test Circuit 1) E_{AS} test Circuit



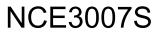
2) Gate charge test Circuit



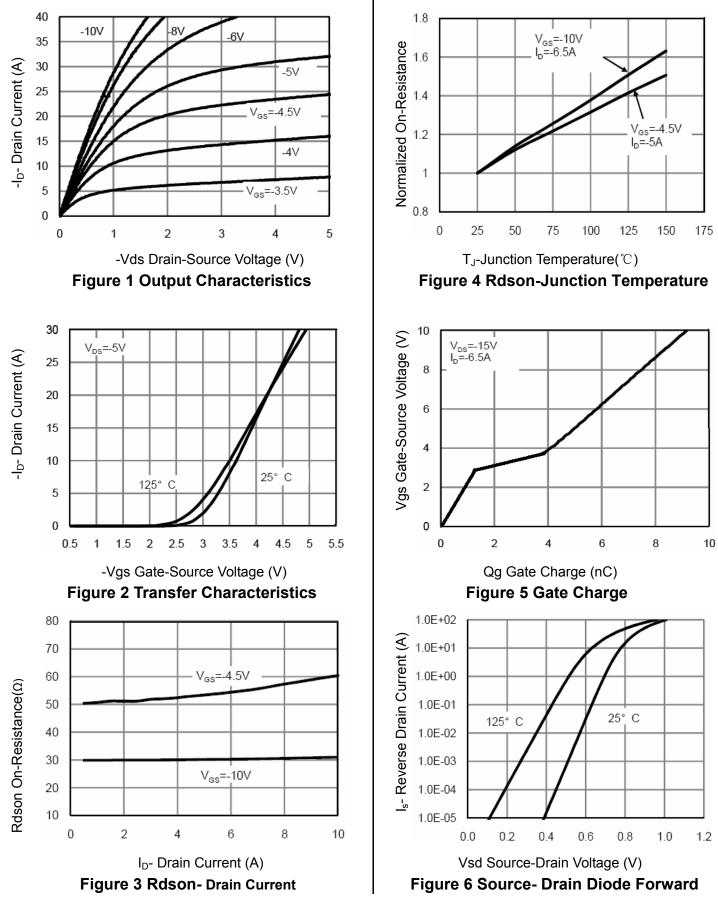
3) Switch Time Test Circuit







Typical Electrical and Thermal Characteristics (Curves)

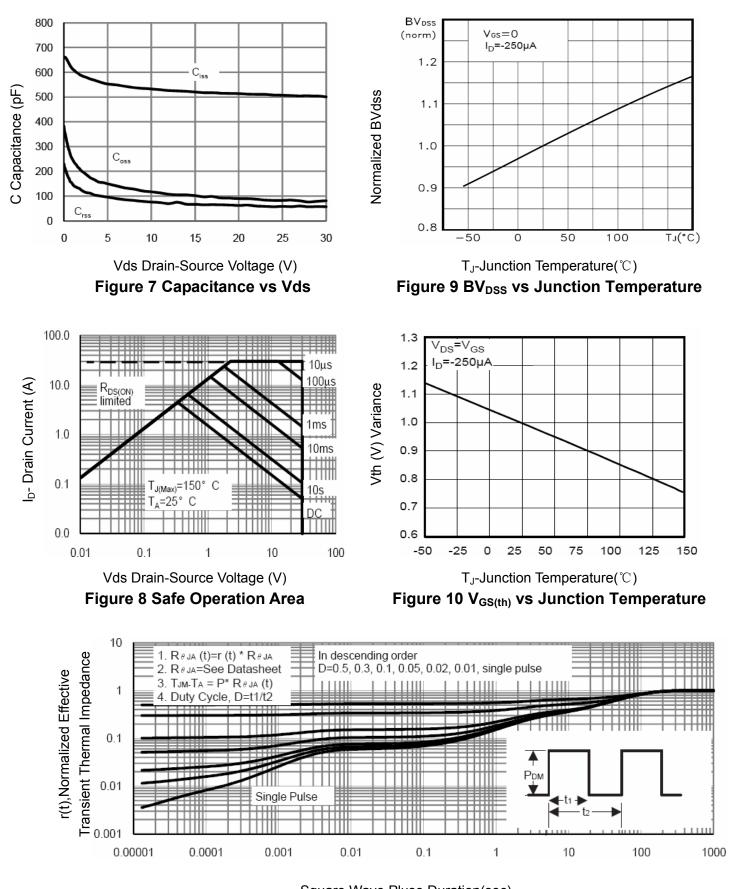




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NCE3007S



Square Wave Pluse Duration(sec)
Figure 11 Normalized Maximum Transient Thermal Impedance

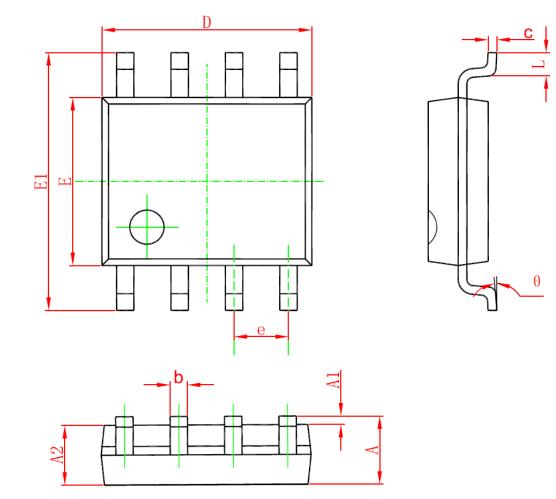


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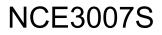
SOP-8 Package Information



Cumb a l	Dimensions In Millimeters		Dimensions In Inches		
Symbol	Min	Max	Min	Max	
A	1. 350	1. 750	0. 053	0. 069	
A1	0. 100	0. 250	0.004	0. 010	
A2	1. 350	1. 550	0. 053	0. 061	
b	0. 330	0. 510	0.013	0. 020	
С	0. 170	0. 250	0.006	0. 010	
D	4. 700	5. 100	0. 185	0. 200	
E	3.800	4.000	0. 150	0. 157	
E1	5. 800	6. 200	0. 228	0. 244	
e	1. 270 (BSC)		0. 050 (BSC)		
L	0. 400	1. 270	0.016	0. 050	
θ	0°	8°	0°	8°	







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